NSN 5962-01-351-6248

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View Online at https://aerobasegroup.com/nsn/5962-01-351-6248
Overall Height:
0.400 inches
Body Length:
1.280 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.185 inches
Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Radar set an/sps-4 (v) 7
Features Provided:
Hermetically sealed and burn in and monolithic and electrostatic sensitive and ultraviolet erasable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
22 input
Case Outline Source And Designator:
D-9 mil-m-38510
Current Rating Per Characteristic:
100.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder

Product Name:

And-or-logic array

Voltage Rating And Type Per Characteristic:

0.5 volts output logic low and 7.0 volts power source

Capitance Rating Per Characteristic:

10.00 input picofarads and 10.00 output picofarads

Time Rating Per Chacteristic:

25.00 nanoseconds delay

Memory Device Type:

Pal

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Test	Data	Document	ŀ
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96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0